

Article | Received 19 May 2026; Revised 4 July 2026; Accepted 23 July 2026; Published 18 August 2026
<https://doi.org/10.55092/aimat20260009>

Highly vertically oriented 2D/3D tin perovskite films for efficient and stable solar cells



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1. Computational methods

1.1. Electrical conductivity calculation

The conductivity of perovskite film from the current-voltage (*I*-*V*) characteristic curves was calculated by Equation (1)

$$\sigma = \frac{I}{V} \times \frac{d}{S} \quad (1)$$

where $\frac{I}{V}$ is the slope of lines in conductivity, *d* and *S* are the thickness and area of perovskite film.

1.2. Hermans' orientation factor (*HF*) calculation

The Hermans orientation factor *H*(100) of the (100) can be calculated using Equation (2) and Equation (3).

$$\langle \cos^2 \varphi \rangle = \frac{\int_0^{\frac{\pi}{2}} I(\varphi) \cos^2 \varphi \, d\varphi}{\int_0^{\frac{\pi}{2}} I(\varphi) \sin \varphi \, d\varphi} \quad (2)$$



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$$H(100) = \frac{3\cos^2\phi - 1}{2} \quad (3)$$

where $I(\phi)$ is the scattering intensity along the (100) ring at the angle ϕ with respect to the reference axis. HF equals 1 indicating that the normal of (100) planes is perfectly along the reference axis and equals 0 suggests that (100) planes are randomly oriented, which will display discrete Bragg spots and uniform rings on GIWAXS patterns, respectively.

1.3. Steady-state decay lifetime calculation

The exciton lifetime of the perovskite films can be derived from the femtosecond transient absorption spectroscopy (TAS) by a bi-exponential fitting as shown in Equation (4).

$$y = A_1 e^{\left(-\frac{\tau}{\tau_1}\right)} + A_2 e^{\left(-\frac{\tau}{\tau_2}\right)} \quad (4)$$

where τ is the exciton lifetime, τ_1 and τ_2 are the decay components of the trap-assisted and radiative recombination process respectively. The carrier recombination lifetime can be calculated by Equation (5).

$$\tau = \frac{A_1 \tau_1^2 + A_2 \tau_2^2}{A_1 \tau_1 + A_2 \tau_2} \quad (5)$$

2. Analyzation of space-charge-limited current (SCLC) model

The trap density (N_t) of perovskite films from the dark J - V curves of the electron-only and hole-only devices can be calculated by Equation (6).

$$N_t = \frac{2\epsilon\epsilon_0 V_{TFL}}{qd^2} \quad (6)$$

where q is the electron charge, d is the thickness of perovskite film, ϵ_0 and ϵ are the vacuum permittivity and relative dielectric constant of perovskite, and V_{TFL} is ordinate of the intersection of ohmic region and trap-filling limited region.

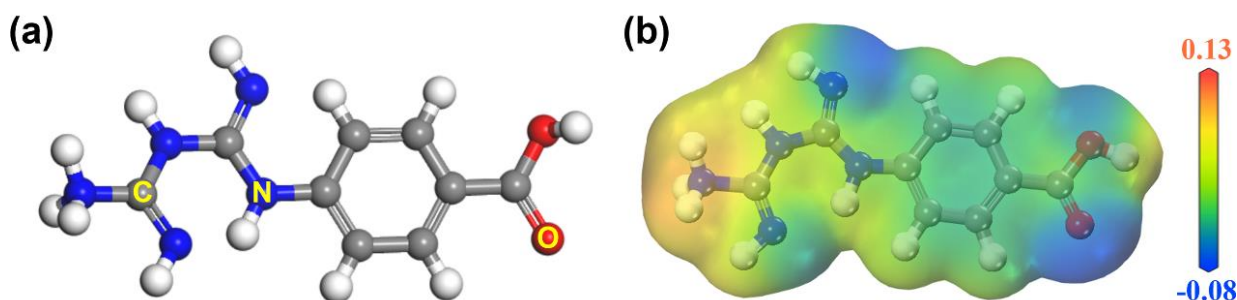


Figure S1. Molecular structure and electrostatic potential diagrams of p-BGBA.

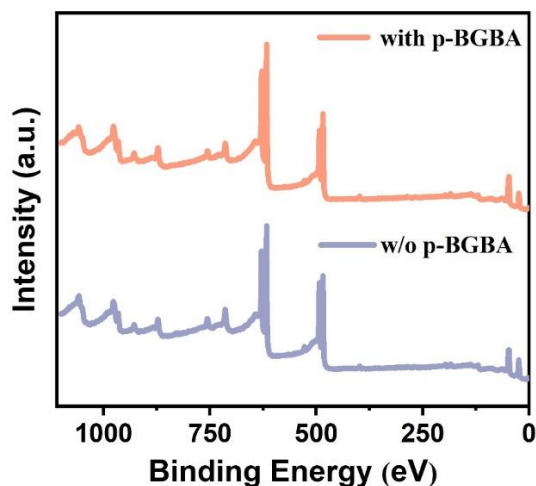


Figure S2. Full XPS spectra of perovskite films without and with p-BGBA.

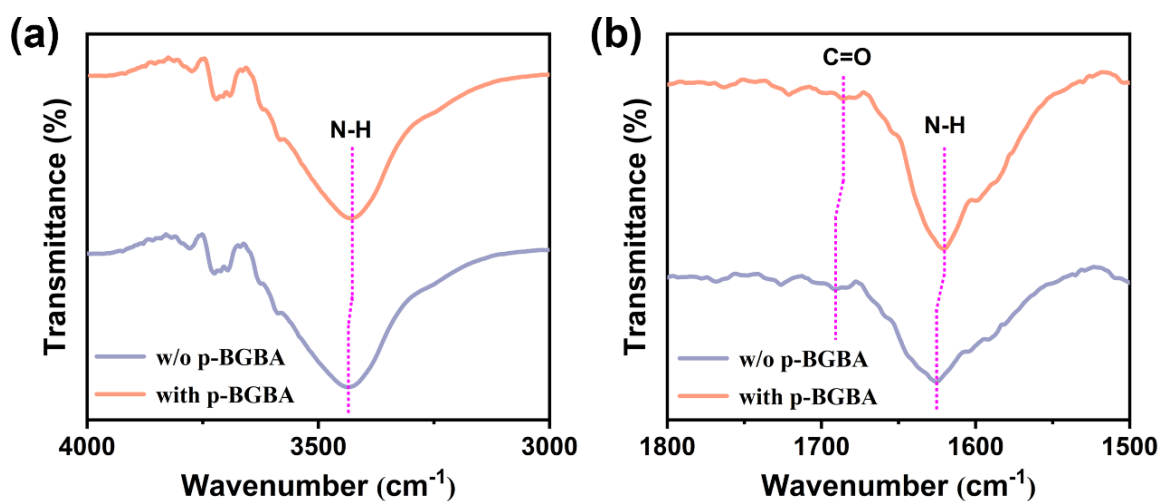


Figure S3. FTIR spectra of the perovskite films without and with p-BGBA. (a) N-H stretching region and (b) C = O stretching and N-H bending vibration regions.

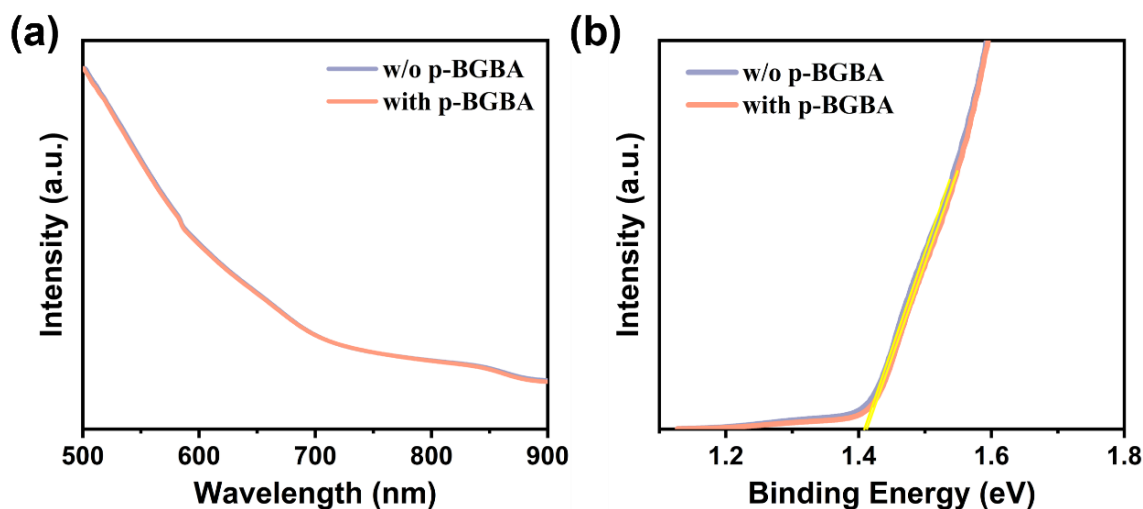


Figure S4. Optical properties of p-BGBA modified perovskite films. (a) UV-vis absorption spectra, and (b) Tauc-plot of perovskite films without and with p-BGBA.

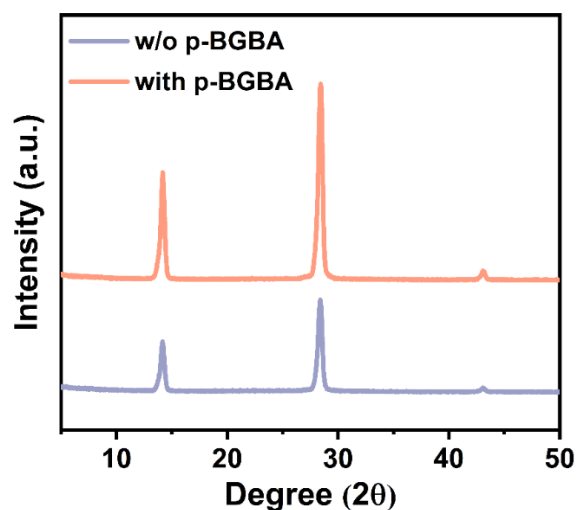


Figure S5. XRD patterns for tin perovskite films without and with p-BGBA.

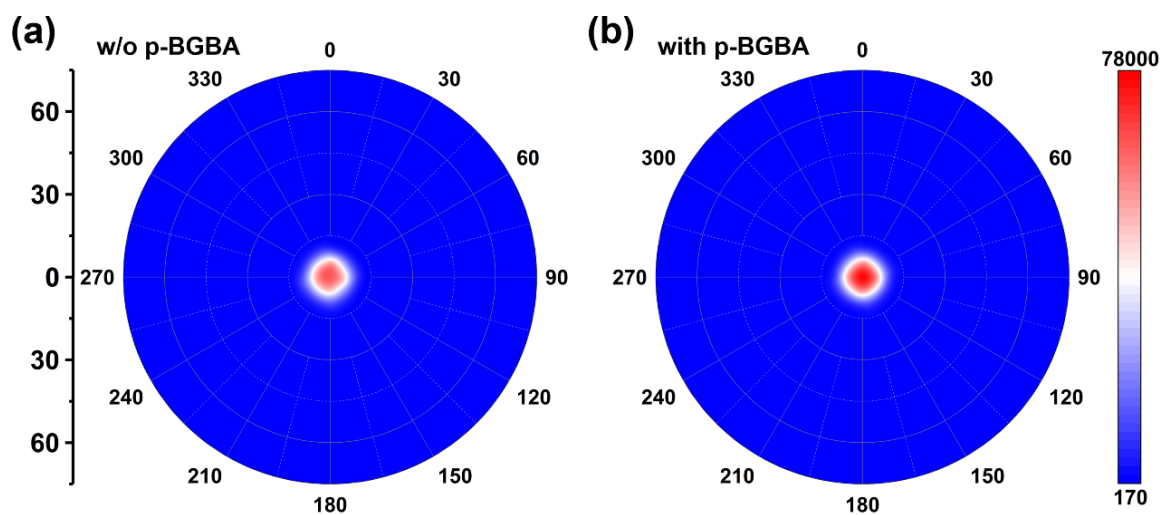


Figure S6. Polar diagrams of the (100) crystal facet of perovskite films without (a) and with (b) p-BGBA.

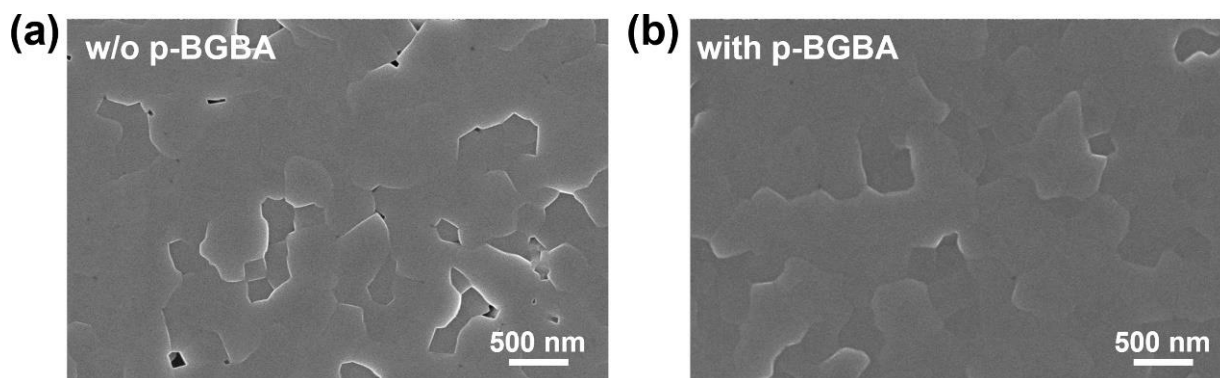


Figure S7. SEM images of perovskite films. (a) Without and (b) with p-BGBA.

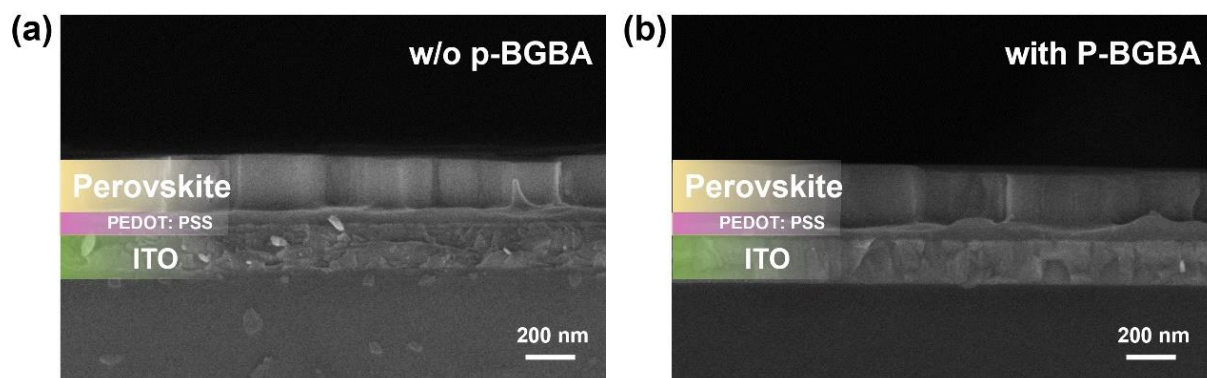


Figure S8. Cross-sectional SEM images of perovskite films. (a) Without and (b) with p-BGBA.

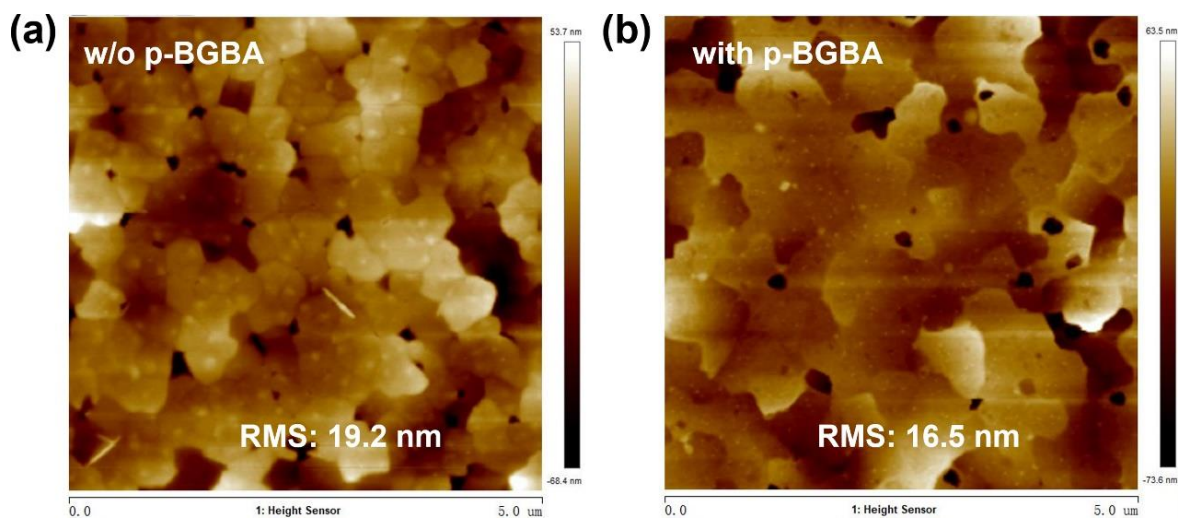


Figure S9. AFM images of perovskite films. (a) Without and (b) with p-BGBA.

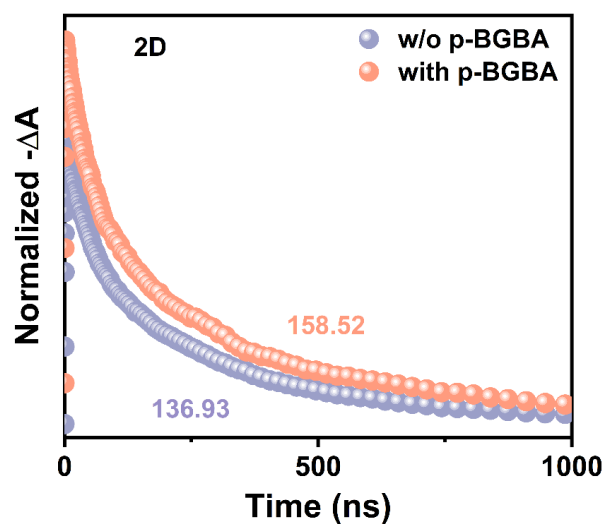


Figure S10. Dynamic transient absorption (TA) decay of the 2D phase.

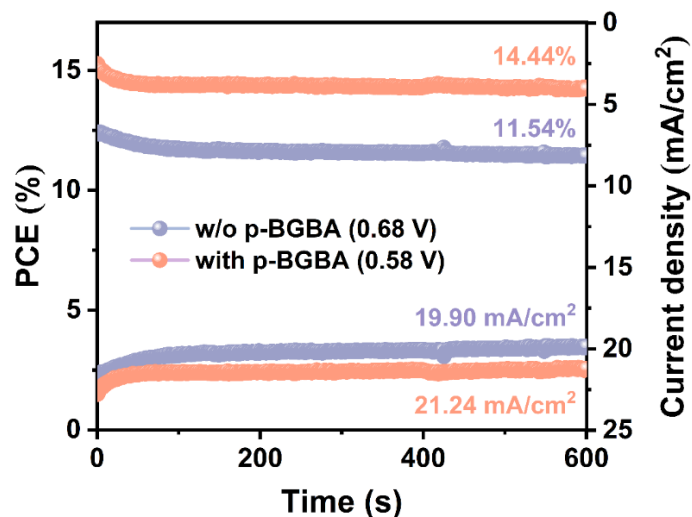


Figure S11. Steady-state power output at the maximum power point.

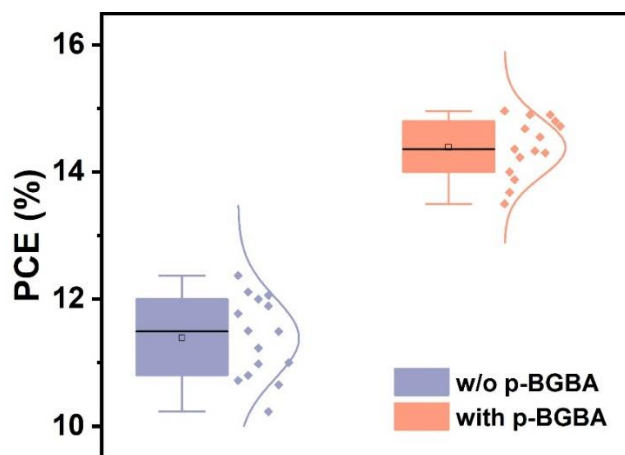


Figure S12. Statistical distribution of the PCEs for 15 tin PSCs without and with p-BGBA.

Table S1. TRPL fitting parameters for perovskite films without and with p-BGBA.

Sample	A_1	τ_1 (ns)	A_2	τ_2 (ns)	τ_{ave} (ns)
w/o p-BGBA	0.62	13.94	0.38	25.26	18.24 ± 1.02
with p-BGBA	0.64	20.63	0.36	49.82	31.14 ± 0.91

Table S2. TA fitting parameters of the perovskite films without and with p-BGBA.

Sample	Phase	A_1	τ_1 (ps)	A_2	τ_2 (ps)	τ_{ave} (ps)
w/o p-BGBA	2D	0.47	33.09	0.53	229.02	136.93
	3D	0.17	9.11	0.83	120.21	101.32
with p-BGBA	2D	0.50	37.72	0.50	279.32	158.52
	3D	0.20	11.51	0.80	183.15	148.82